## **PCP1405**



http://onsemi.com

# Power MOSFET 250V, 6.5Ω, 0.6A, Single N-Channel

#### **Features**

- On-resistance  $R_{DS}(on)1=5\Omega$  (typ)
- 2.5V drive
- Protection diode in
- Halogen free compliance

## **Specifications**

**Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Value	Unit
Drain to Source Voltage	V <sub>DSS</sub>		250	V
Gate to Source Voltage	VGSS		±10	V
Drain to Gate Voltage	V <sub>DGS</sub>		250	V
Gate to Drain Voltage	V <sub>GDS</sub>		±10	V
Drain Current (DC)	ID		0.6	Α
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10μs, duty cycle≤1%	2.4	Α
Power Dissipation		Tc=25°C	3.5	W
	PD	When mounted on ceramic substrate (600mm <sup>2</sup> ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **Thermal Resistance Ratings**

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Parameter	Symbol	Value	Unit
Junction to Case Steady State	$R_{ heta JC}$	35.7	
Junction to Ambient When mounted on ceramic substrate (600mm²×0.8mm)	$R_{ heta JA}$	96.1	°C/W

## **Electrical Characteristics** at Ta = 25°C

Parameter	0 1 1	Symbol Conditions	Value			11.2
	Symbol		min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V	250			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =250V, V <sub>GS</sub> =0V			1	μА
Gate to Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μА
Gate Threshold Voltage	VGS(th)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	0.4		1.3	V
Forward Transconductance	gFS	V <sub>DS</sub> =10V, I <sub>D</sub> =0.3A		1.4		S

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#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

## **PCP1405**

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Parameter	Cumbal	Con distant	Value			I I a it
Parameter	Symbol	Conditions	min	typ	max	Unit
Static Drain to Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =0.3A, V <sub>GS</sub> =4.5V		5	6.5	Ω
	R <sub>DS</sub> (on)2	I <sub>D</sub> =0.3A, V <sub>GS</sub> =2.5V		5.1	7.2	Ω
Input Capacitance	Ciss			140		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		8		pF
Reverse Transfer Capacitance	Crss			3		pF
Turn-ON Delay Time	t <sub>d</sub> (on)			7.6		ns
Rise Time	t <sub>r</sub>	0		7.8		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit		19		ns
Fall Time	tf			26		ns
Total Gate Charge	Qg			2.1		nC
Gate to Source Charge	Qgs	V <sub>DS</sub> =125V, V <sub>GS</sub> =4.5V, I <sub>D</sub> =0.6A		0.3		nC
Gate to Drain "Miller" Charge	Qgd			0.7		nC
Forward Diode Voltage	V <sub>SD</sub>	I <sub>S</sub> =0.6A, V <sub>GS</sub> =0V		0.84	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **Ordering & Package Information**

Device	Package	Shipping	note
PCP1405-TD-H	PCP, SC-62 SOT-89, TO-243	1,000 pcs. / reel	Pb-Free and Halogen Free

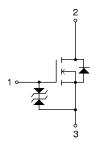
## Packing Type:TD



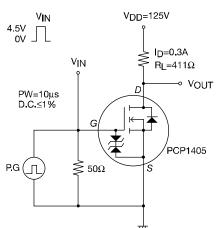
## Marking

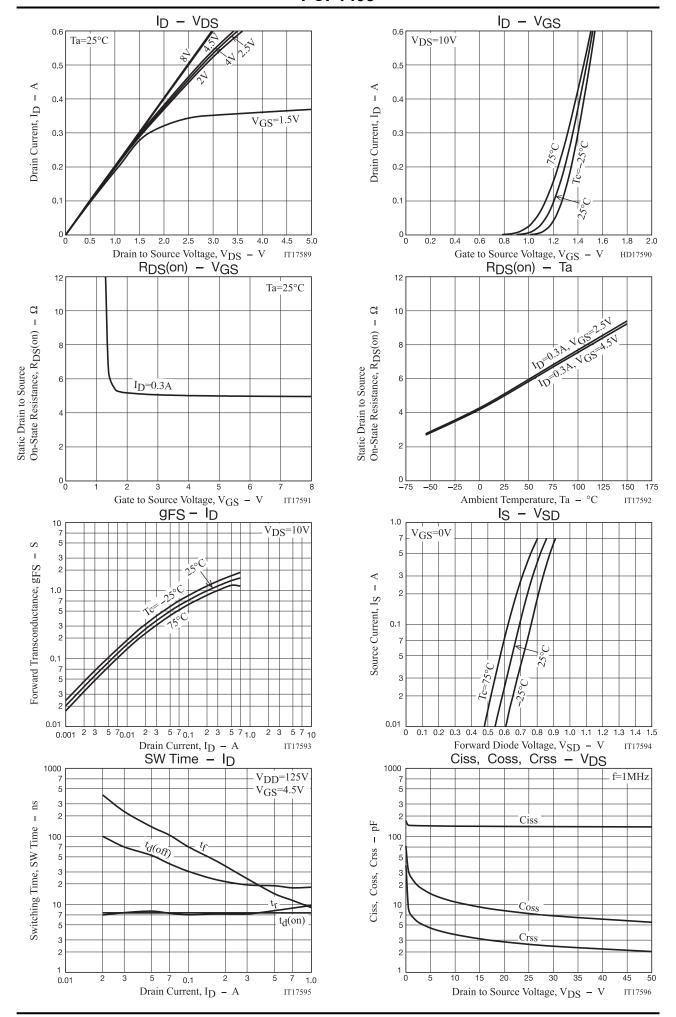


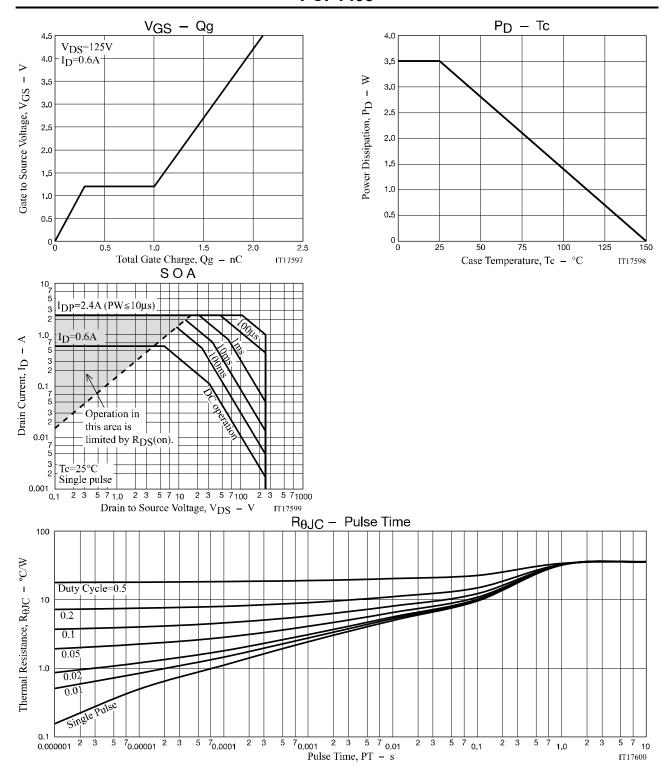
## **Electrical Connection**



## **Switching Time Test Circuit**







### **Package Dimensions**

PCP1405-TD-H

#### SOT-89/PCP-1

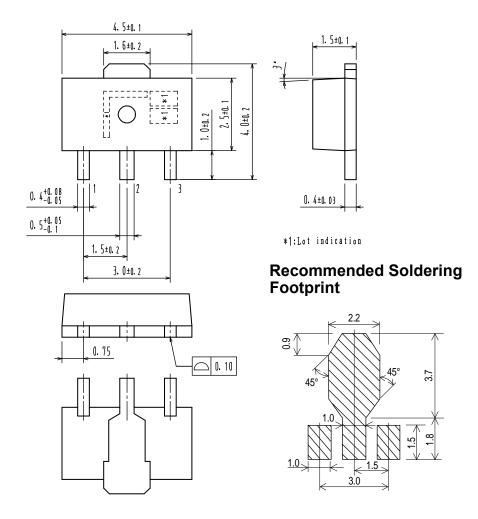
CASE 419AU ISSUE O

unit: mm

1: Gate

2: Drain

3: Source



Note on usage: Since the PCP1405 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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